Roughening By Impurities At Finite Temperatures

In a recent Letter¹ Huse and Henley examined roughening of interfaces by random coupling energies. In particular, on the basis of numerical simulations, they concluded that at zero temperature, in two dimensions, fluctuations y of an interface scale with its dimensions, fluctuations y of an interface scale with it
length x as $y \sim x^{\zeta}$, with $\zeta = \frac{2}{3}$. Also the fluctuation in energy gain ΔE of the rough wall from the weaker in energy gain ΔE of the rough wall from the weake bonds scale as x^x with $x \approx \frac{1}{3}$. Do these exponent (presumably universal) apply to a different model of interfaces; and are they applicable to finite temperatures (in principle, entropy effects could alter the scaling)? Numerical simulations at finite temperature in-

 $W(x+1,y) = \exp[-\mu(x,y)] [W(x,y) + \gamma W(x,y-1)]$

with $W(0, y) = \delta_{\gamma, 0}$. For each realization of randomness, the $T=0$ optimal value op($y(x)$) corresponds to the path terminating at x with the largest weight, while at finite T the mean $\langle y(x) \rangle$ is obtained by averaging over the weights $W(x, y)$. Numerical results are plotted in Fig. 1 for $\sigma^2 = \frac{5}{6}$, with $\gamma = 1.0$ and $\gamma = 0.1$. The quenched random averaging in $y_0 = \overline{\left[\text{op}(y(x))^2\right]}^{1/2}$
and $y_m = \left[\left(y(x)\right)^2\right]^{1/2}$ is performed by summing over 400 different realizations. Dashed lines are fits by power laws $y \sim x^{\xi}$. The exponents for y_0 and y_m are 0.64 and 0.67 for $\gamma = 1.0$, and 0.62 and 0.67 for $y=0.1$. They are in agreement with $\zeta \approx \frac{2}{3}$ of Ref. 1 suggesting that ζ is indeed universal and applicable to finite T. In contrast to nonrandom systems, fluctuations are smaller at finite T (although the scaling is the same). Since there are more paths to smaller y , entropy effects tend to reduce $\langle y \rangle$. Therefore, roughness

FIG. 1. Fluctuations of an impurity-roughened wall.

dicate that the answers are in the affirmative.

Interfaces consider here are defined on a lattice, and at zero temperature, and in the absence of impurities are straight lines through $y=0$. At a finite temperature T or because of impurities the interface fluctuates, and its configuration is described by the integer heights $y(x)$. Overhangs and islands are ignored, and only configurations with $|y(x+1)-y(x)| = 0$ or 1 are allowed (the solid-on-solid or SOS model). $|y(x+1)|$ $-y(x) = 1$ corresponds to a broken bond in the x direction, with an energy cost E_0 (a Boltzman weight $y = e^{-E_0}$. The bonds $\mu(x, y)$ in the y direction are independent random variables of variance σ^2 . The interface begins at $x=0$, $y=0$; and at finite T, the total weight $W(x, y)$ of paths connecting $(0,0)$ to (x, y) is calculated recursively from

 $+\gamma W(x, y+1)$],

of the interface at short length scales is smoothed out at finite T. At infinite temperatures, disorder $(\sigma \sim 1/T)$ disappears, and fluctuations characteristic of a uniform interface $(\langle y \rangle = 0, \langle y^2 \rangle = x)$ are expected. The nonrandom exponent of $\frac{1}{2}$ describes smoother fluctuations. Dimensional arguments² indicate that crossover to impurity-dominated roughening occurs at ength scales larger than $x_d \approx \gamma/\sigma^2$. Also important are the fluctuations in energy gain $\Delta E(x)$ from random bonds. Huse and Henley find $\Delta E(x) \sim x^x$, with $\chi \approx \frac{1}{3}$. A similar exponent was obtained for the optimal paths in the above SOS model. The analogue of $\Delta E(x)$ at finite T is the constrained free energy $\Delta F(x,y)$ for paths from $(0,0)$ to (x,y) . Again $\Delta F(x, y)$ for pains from $(0,0)$ to (x, y) . Again $\Delta F(x, \langle y \rangle)$ scales as x^x with $x \approx \frac{1}{3}$; i.e., the free energy is dominated by the energy, and entropy effects are secondary. Extending the results to finite T is actually a necessary step in an indirect proof presented elsewhere² that the exponent ζ is exactly $\frac{2}{3}$, and provides a connection with the direct proof in the following Comment.

This research was supported by the National Science Foundation through Grant No. DMR 82-07431. The author acknowledges conversations with B. Halperin and D. Nelson.

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(Received 3 July 1985)

PACS numbers: 75.60.Ch, 05.50.+q, 75.10.Hk, 82.65.Dp

¹D. A. Huse and C. L. Henley, Phys. Rev. Lett. 54, 2708 (1985).

M. Kardar and D. R. Nelson, Phys. Rev. Lett. 55, 1157 (1985).